Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3292	(drain adj2 (potential or voltage)) near5 (stabiliz\$6 or regulat\$6 or supply\$3 or amplif\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:47
L4	46749	(conduct\$4 or metal) adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:19
L6	495467	(feed\$4 adj back) or feedback	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:17
L7	8	(CRIPPA near2 LUCA).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L8	3	(RAGONE near2 GIANCARLO).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L9	370	365/185.02	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L10	1774	365/185.03	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L11	1189	365/185.28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L12	3482	365/189.09	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:19
L13	2291	365/185.18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:20
L14	1913573	(program\$4 or writ\$4) .	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:20
L15	348	1 same 14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:21

L17	14	6 same 15	US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR	ON	2005/11/04 10:43
L18	478412	(electrically adj3 memory) or (erasable adj3 memory) or (\$1eprom) or (flash or non-volatile or (non adj volatile) adj3 (memory or cell)) or ((non adj volatile) or nonvolatile or non-volatile) adj3 (memory or cell) or nvm	IBM_TDB US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:22
L19	173	1 same 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:44
L22	142024 ·	14 same 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:46
L23	270	22 same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:46
L24	1204	22 same 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:46
L26	29448	(drain adj2 (potential or voltage))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:47
L27	7	26 same 23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/1,1/04 10:53
L28	13	26 same 24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:51
L29	1707	26 same 22′	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:51
L30	58	29 and 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:53
L31	265	4 same 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:54
L38	2856	24 or 29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 10:59

L39	62	38 and 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:00
L40	249	38 and 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:00
L41	236	38 and 11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:00
L4 <u>2</u>	141	38 and 12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:00
L43	353	38 and 13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 11:00
L45	21076	conductor.clm.	US-PGPUB	OR	ON	2005/11/04 11:18
L46	16530	((feed\$4 adj back) or feedback).clm.	US-PGPUB	OR	ON	2005/11/04 11:18
L47	6818	(((non adj volatile) or nonvolatile or non-volatile) adj2 memory).clm.	US-PGPUB	OR	ON	2005/11/04 11:18
L48	110	(drain adj2 (potential or voltage)) near5 (stabiliz\$6 or regulat\$6 or supply\$3 or amplif\$6 or generat\$6).clm.	US-PGPUB	OR	ON	2005/11/04 11:18
L49	2233	((conduct\$4 or metal) adj line).clm.	US-PGPUB	OR	ON	2005/11/04 11:20
L50	30	46 and 49	US-PGPUB	OR	ON	2005/11/04 11:21
L51	347	45 and 46	US-PGPUB	OR	ON	2005/11/04 11:21
L52	3	51 and 47	US-PGPUB	OR	ON	2005/11/04 11:21
L53	0	51 and 48	US-PGPUB	OR	ON	2005/11/04 11:21
L54	16468	((electrically adj3 memory) or (erasable adj3 memory) or (\$1eprom) or (flash or non-volatile or (non adj volatile) adj3 (memory or cell)) or ((non adj volatile) or nonvolatile or non-volatile) adj3 (memory or cell) or nvm).clm.	US-PGPUB	OR	ON	2005/11/04 11:23
L55	8	51 and 54	US-PGPUB	OR	ON	2005/11/04 11:23